

# PC924

## OPIC Photocoupler for IGBT Drive of Inverter

※ Lead forming type (I type) and taping reel type (P type) are also available. (PC924I/PC924P)

※※ TÜV (VDE 0884) approved type is also available as an option.

### ■ Features

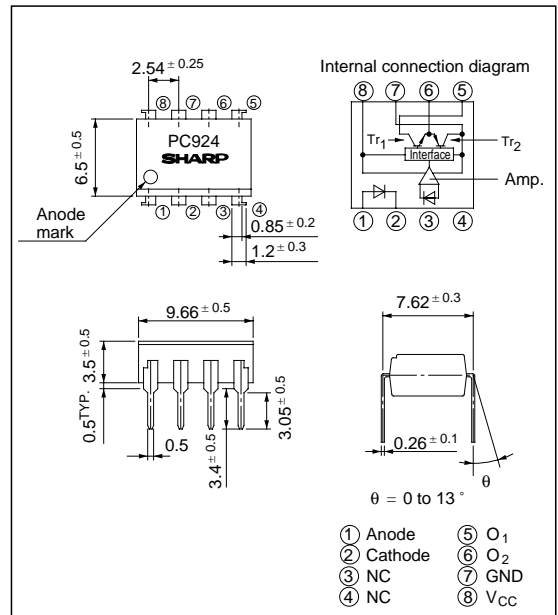
1. Built-in direct drive circuit for IGBT drive  
( $I_{O1P}$ ,  $I_{O2P}$  : 0.4A)
2. High speed response ( $t_{PLH}$ ,  $t_{PHL}$  : MAX. 2.0  $\mu$ s)
3. Wide operating supply voltage range  
( $V_{CC}$  : 15 to 30V at  $T_a = -10$  to 60°C)
4. High noise resistance type  
 $CM_H$  : MIN. -1 500V/ $\mu$ s  
 $CM_L$  : MIN. 1 500V/ $\mu$ s
5. High isolation voltage ( $V_{iso}$  : 5 000V<sub>rms</sub>)

### ■ Applications

1. IGBT drive for inverter control

### ■ Outline Dimensions

(Unit : mm)



\* "OPIC" (Optical IC) is a trademark of the SHARP Corporation.

An OPIC consists of a light-detecting element and signal-processing circuit integrated onto a single chip.

### ■ Absolute Maximum Ratings

(Unless specified,  $T_a = T_{opr}$ )

	Parameter	Symbol	Rating	Unit
Input	Forward current	$I_F$	25	mA
	Reverse voltage	$V_R$	6	V
	Supply voltage	$V_{CC}$	35	V
Output	$O_1$ output current	$I_{O1}$	0.1	A
	*1 $O_1$ peak output current	$I_{O1P}$	0.4	A
	$O_2$ output current	$I_{O2}$	0.1	A
	*1 $O_2$ peak output current	$I_{O2P}$	0.4	A
	$O_1$ output voltage	$V_{O1}$	35	V
	Power dissipation	$P_O$	500	mW
	Total power dissipation	$P_{tot}$	550	mW
	*2 Isolation voltage	$V_{iso}$	5 000	V <sub>rms</sub>
Operating temperature	$T_{opr}$	- 25 to + 80	°C	
Storage temperature	$T_{stg}$	- 55 to + 125	°C	
*3 Soldering temperature	$T_{sol}$	260	°C	

\*1 Pulse width  $\leq 0.15 \mu$ s,

Duty ratio : 0.01

\*2 40 to 60% RH, AC for 1 minute,  $T_a = 25^\circ$ C

\*3 For 10 seconds

## Electro-optical Characteristics

( Ta = T<sub>opr</sub> unless otherwise specified )

Parameter		Symbol	*4 Conditions	MIN.	TYP.	MAX.	Unit	Fig.			
Input	Forward voltage	V <sub>F1</sub>	Ta = 25°C, I <sub>F</sub> = 20mA	-	1.2	1.4	V	-			
		V <sub>F2</sub>	Ta = 25°C, I <sub>F</sub> = 0.2mA	0.6	0.9	-	V	-			
	Reverse current	I <sub>R</sub>	Ta = 25°C, V <sub>R</sub> = 4V	-	-	10	μA	-			
	Terminal capacitance	C <sub>t</sub>	Ta = 25°C, V = 0, f = 1kHz	-	30	250	pF	-			
Output	Operating supply voltage	V <sub>CC</sub>	Ta = - 10 to 60°C	15	-	30	V	-			
				15	-	24	V				
	O <sub>1</sub> low level output voltage	V <sub>O1L</sub>	V <sub>CC1</sub> = 12V, V <sub>CC2</sub> = - 12V I <sub>O1</sub> = 0.1A, I <sub>F</sub> = 10mA	-	0.2	0.4	V	1			
	O <sub>2</sub> high level output voltage	V <sub>O2H</sub>	V <sub>CC</sub> = V <sub>O1</sub> = 24V, I <sub>O2</sub> = - 0.1A, I <sub>F</sub> = 10mA	18	21	-	V	2			
	O <sub>2</sub> low level output voltage	V <sub>O2L</sub>	V <sub>CC</sub> = 24V, I <sub>O2</sub> = 0.1A, I <sub>F</sub> = 0	-	1.2	2.0	V	3			
	O <sub>1</sub> leak current	I <sub>O1L</sub>	Ta = 25°C, V <sub>CC</sub> = V <sub>O1</sub> = 35V, I <sub>F</sub> = 0	-	-	500	μA	4			
	O <sub>2</sub> leak current	I <sub>O2L</sub>	Ta = 25°C, V <sub>CC</sub> = V <sub>O2</sub> = 35V, I <sub>F</sub> = 10mA	-	-	500	μA	5			
	High level supply current	I <sub>CCH</sub>	Ta = 25°C, V <sub>CC</sub> = 24V, I <sub>F</sub> = 10mA	-	6	10	mA	6			
V <sub>CC</sub> = 24V, I <sub>F</sub> = 10mA			-	-	14	mA					
Ta = 25°C, V <sub>CC</sub> = 24V, I <sub>F</sub> = 0			-	8	13	mA					
Low level supply current	I <sub>CCL</sub>	Ta = 25°C, V <sub>CC</sub> = 24V, I <sub>F</sub> = 0	-	-	17	mA	6				
		V <sub>CC</sub> = 24V, I <sub>F</sub> = 0	-	-	17	mA					
Transfer characteristics	*5 “Low→High” threshold input current	I <sub>FLH</sub>	Ta = 25°C, V <sub>CC</sub> = 24V	1.0	4.0	7.0	mA	7			
			V <sub>CC</sub> = 24V	0.6	-	10.0	mA				
	Response time	Isolation resistance	R <sub>ISO</sub>	Ta = 25°C, DC = 500V, 40 to 60% RH	5 x 10 <sup>10</sup>	10 <sup>11</sup>	-	Ω	-		
				“Low→High” propagation delay time	t <sub>PLH</sub>	-	1.0	2.0	μs	8	
				“High→Low” propagation delay time	t <sub>PHL</sub>	Ta = 25°C, V <sub>CC</sub> = 24V, I <sub>F</sub> = 10mA	-	1.0	2.0		μs
				Rise time	t <sub>r</sub>	R <sub>C</sub> = 47 Ω, C <sub>G</sub> = 3,000pF	-	0.2	0.5		μs
	Fall time	t <sub>f</sub>		-	0.2	0.5	μs				
	Instantaneous common mode rejection voltage “Output: High level”	CM <sub>H</sub>	Ta = 25°C, V <sub>CM</sub> = 600V(peak) I <sub>F</sub> = 10mA, V <sub>CC</sub> = 24V, ΔV <sub>O2H</sub> = 2.0V	-	- 30	-	kV/μs	9			
Instantaneous common mode rejection voltage “Output: Low level”			CM <sub>L</sub>	Ta = 25°C, V <sub>CM</sub> = 600V(peak) I <sub>F</sub> = 0, V <sub>CC</sub> = 24V, ΔV <sub>O2L</sub> = 2.0V	-	30	-		kV/μs		

\*4 When measuring output and transfer characteristics, connect a by-pass capacitor ( 0.01 μF or more ) between V<sub>CC</sub> and GND near the device.

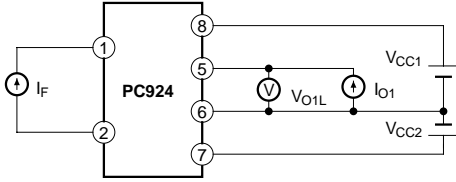
\*5 I<sub>FLH</sub> represents forward current when output goes from “Low” to “High” .

## Truth Table

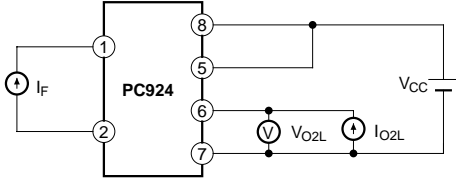
Input	O <sub>2</sub> Output	Tr. 1	Tr. 2
ON	High level	ON	OFF
OFF	Low level	OFF	ON

■ **Test Circuit**

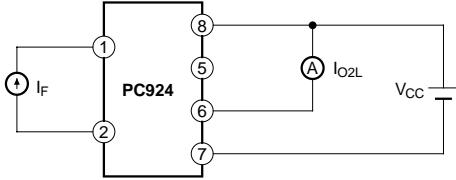
**Fig. 1**



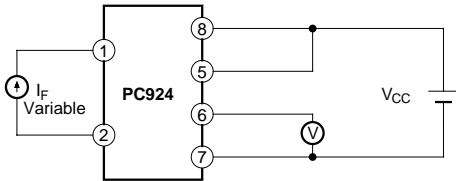
**Fig. 3**



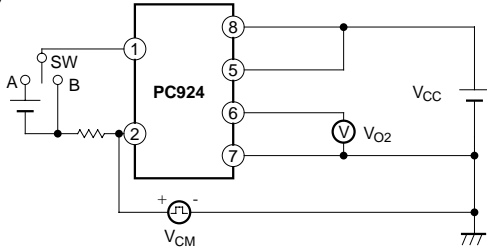
**Fig. 5**



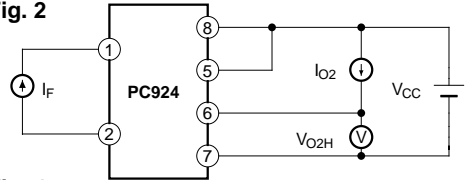
**Fig. 7**



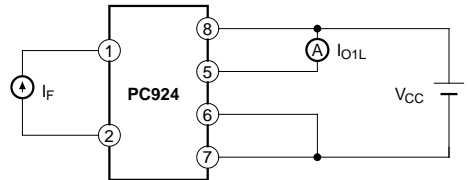
**Fig. 9**



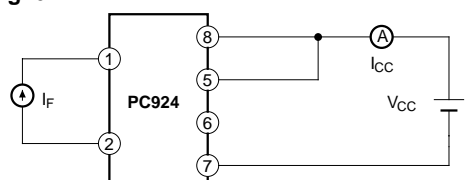
**Fig. 2**



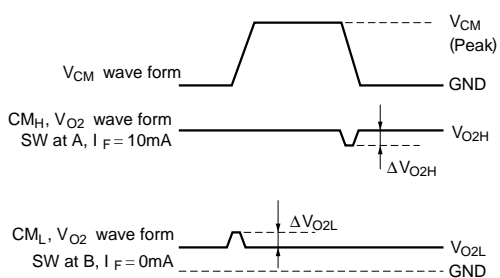
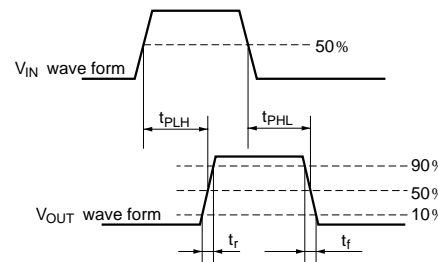
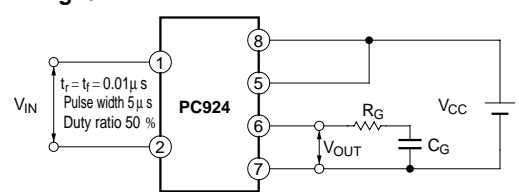
**Fig. 4**



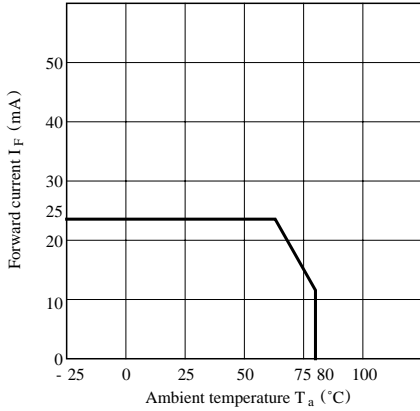
**Fig. 6**



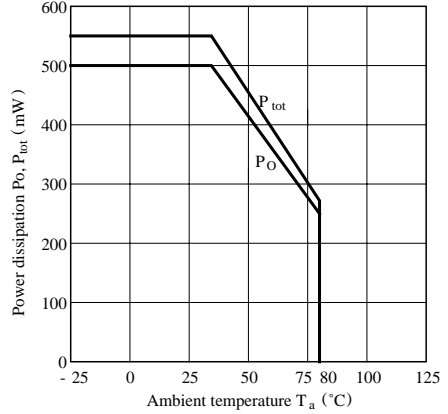
**Fig. 8**



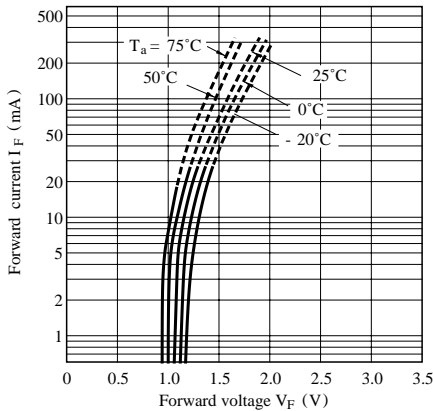
**Fig.10 Forward Current vs. Ambient Temperature**



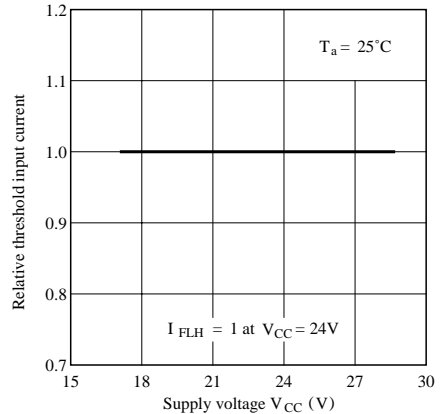
**Fig.11 Power Dissipation vs. Ambient Temperature**



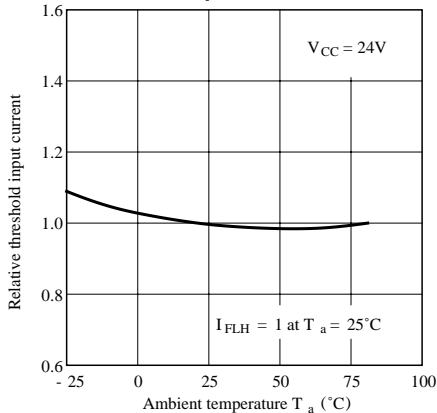
**Fig.12 Forward Current vs. Forward Voltage**



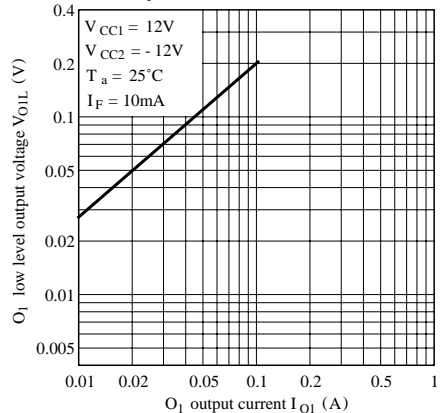
**Fig.13 Relative Threshold Input Current vs. Supply Voltage**



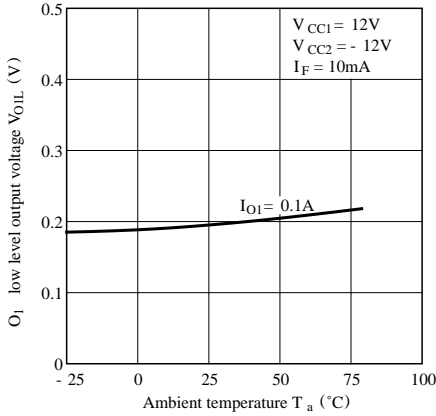
**Fig.14 Relative Threshold Input Current vs. Ambient Temperature**



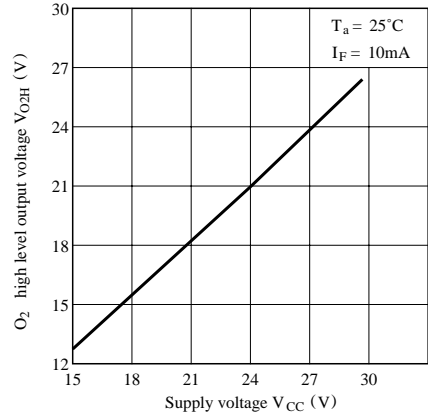
**Fig.15 O<sub>1</sub> Low Level Output Voltage vs. O<sub>1</sub> Output Current**



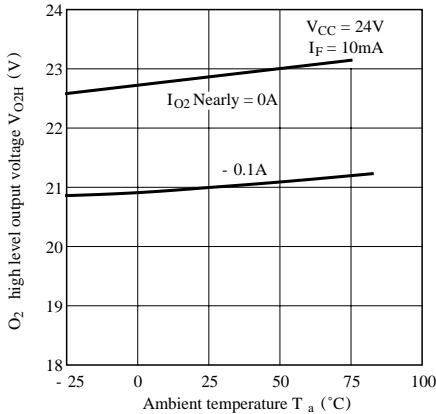
**Fig.16 O<sub>1</sub> Low Level Output Voltage vs. Ambient Temperature**



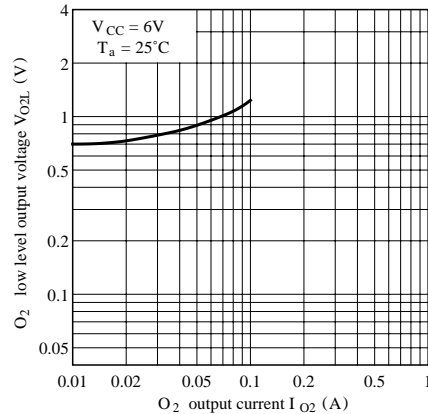
**Fig.17 O<sub>2</sub> High Level Output Voltage vs. Supply Voltage**



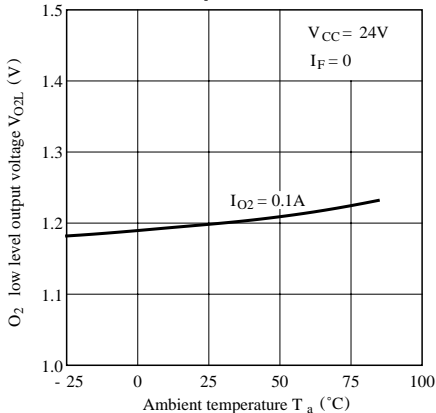
**Fig.18 O<sub>2</sub> High Level Output Voltage vs. Ambient Temperature**



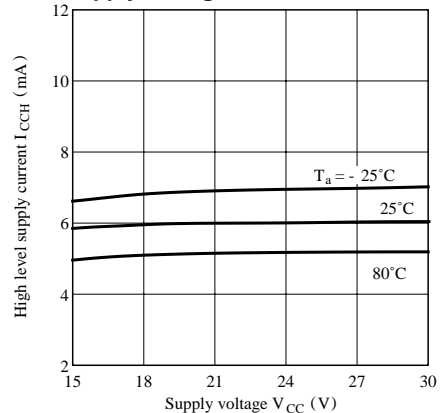
**Fig.19 O<sub>2</sub> Low Level Output Voltage vs. O<sub>2</sub> Output Current**



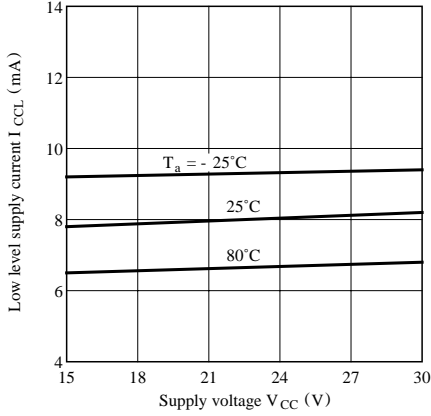
**Fig.20 O<sub>2</sub> Low Level Output Voltage vs. Ambient Temperature**



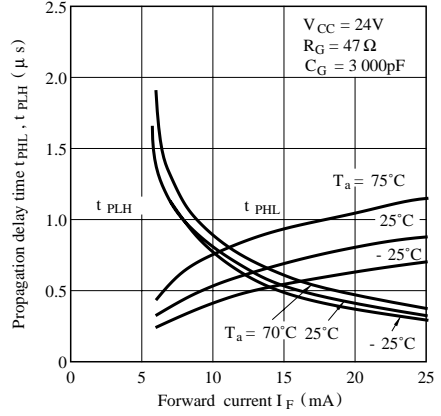
**Fig.21 High Level Supply Current vs. Supply Voltage**



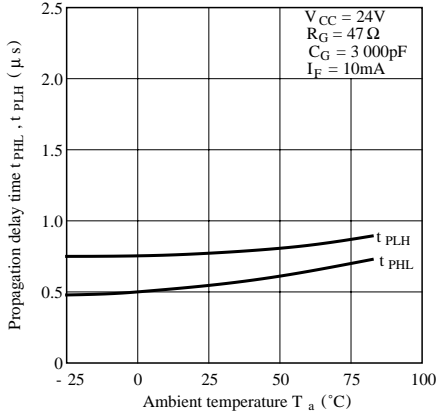
**Fig.22 Low Level Supply Current vs. Supply Voltage**



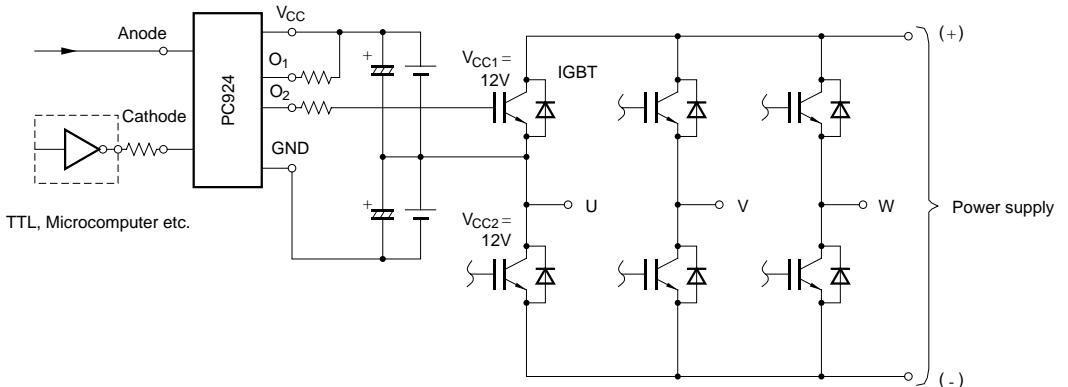
**Fig.23 Propagation Delay Time vs. Forward Current**



**Fig.24 Propagation Delay Time vs. Ambient Temperature**



■ **Application Circuit (IGBT Drive for Inverter)**



● Please refer to the chapter “Precautions for Use”